CLAIMS

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- 1 1. An electrokinetic device, comprising:
- 2 a pumping conduit having a first end and a second end, and including a porous 3 dielectric material,
- a conducting conduit having a first end and a second end, said pumping

 conduit second end and said conducting conduit first end connecting at a junction; and

 an odd number of electrodes in electrical communication with said pumping
- 7 conduit and said conducting conduit.
 - 2. The electrokinetic device of claim 1, wherein said odd number of electrodes comprises a first electrode at potential V1 in electrical communication with said pumping conduit first end, a second electrode at potential V2 in electrical communication with said conduit, and a third electrode at potential V3 in electrical communication with said conducting conduit second end, and wherein V1 does not equal V2.
- The electrokinetic device of claim 2, wherein V3 does not equal V2.
- 1 4. The electrokinetic device of claim 2, wherein V1, V2, and V3 are selected so that (V2 V1) and (V3 V2) are oppositely signed.
 - 5. The electrokinetic device of claim 4, wherein V1 is equal to V3.
- 1 6. The electrokinetic device of claim 5, wherein said potentials V1 and V3 are ground potentials.
- 7. The electrokinetic device of claim 1, wherein said conducting conduitable includes a porous material.
- 1 8. The electrokinetic device of claim 1, wherein said conducting conduit 2 hydrodynamic conductance, k_c , is greater than said pumping conduit hydrodynamic 3 conductance, k_p .
- 1 9. The electrokinetic device of claim 8, wherein $k_c/k_p \ge 2$.
- 1 10. The electrokinetic device of claim 9, wherein $k_c/k_p \ge 10$.
- 1 11. The electrokinetic device of claim 10, wherein $k_c/k_p \ge 100$.
- 1 12. The electrokinetic device of claim 11, wherein $k_c/k_p \ge 1000$.
- 1 13. The electrokinetic device of claim 12, wherein $k_c/k_p \ge 10,000$.
- 1 14. The electrokinetic device of claim 1, wherein said conducting conduit
- 2 electrokinetic pressure value, p_c^{ek} , is less than said pumping conduit electrokinetic
- 3 pressure value, p_{p}^{ek} .
- 1 15. The electrokinetic device of claim 14, wherein $p^{ek} / p^{ek}_{p} \le 0.5$.

- The electrokinetic device of claim 15, wherein $p^{ek} / p^{ek}_{p} \le 0.1$. 16. 1
- The electrokinetic device of claim 16, wherein $p^{ek} / p^{ek}_{p} \le 0.01$. 1 17.
- The electrokinetic device of claim 17, wherein $p^{ek}/p^{ek} \le 0.001$. 18. 1
- The electrokinetic device of claim 18, wherein $p^{ek} / p^{ek} = 0.0001$. 1 19.
- The electrokinetic device of claim 1, wherein said conducting conduit 20. 1
- electrical resistance, R_c , is greater than or equal to said pumping conduit electrical 2 3 resistance, R_p .

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- The electrokinetic device of claim 20, wherein $R_c/R_p \ge 2$. 21. 1
- The electrokinetic device of claim 21, wherein $R_c/R_p \ge 5$. 1 22.
- 23. The electrokinetic device of claim 22, wherein $R_c/R_p \ge 10$. 1
- 24. The electrokinetic device of claim 23, wherein $R_c/R_p \ge 100$. 1
- The electrokinetic device of claim 1, wherein said device is capable of 25. 1 generating 0.1 psi/volt applied across said pumping conduit. 2
- The electrokinetic device of claim 25, wherein said device is capable 1 26. 2 of generating 1 psi/volt applied across said pumping conduit.
 - The electrokinetic device of claim 26, wherein said device is capable 27. of generating 10 psi/volt applied across said pumping conduit.
- An electrokinetic device, comprising: 1 28.
- a first pumping conduit having a first end and a second end, and including a 2 3 first porous dielectric material;
 - a first conducting conduit having a first end and a second end, said first pumping conduit second end and said first conducting conduit first end connecting at a first junction;
 - a second pumping conduit having a first end and a second end, and including a second porous dielectric material, said first conducting conduit second end and said second pumping conduit first end connecting at a second junction; and
 - a first electrode in electrical communication with said first pumping conduit first end, a second electrode in electrical communication with said first junction, a third electrode in electrical communication with said second junction, and a fourth electrode in electrical communication with said second pumping conduit second end,
- wherein said conducting conduit electrokinetic pressure value, p^{ek}_{c} , is less than 14 or equal to the electrokinetic pressure value, p^{ek}_{p} , of at least one of said pumping 15 16 conduits.
 - The electrokinetic device of claim 28 wherein $p^{ek} / p^{ek}_{p} \le 0.5$. 29.

- 1 30. The electrokinetic device of claim 29, wherein $p^{ek} / p^{ek}_{p} \le 0.1$.
- The electrokinetic device of claim 30, wherein $p^{ek} / p^{ek} \ge 0.01$.
- The electrokinetic device of claim 31, wherein $p^{ek} c/p^{ek} p \le 0.001$.
- 1 33. The electrokinetic device of claim 32, wherein $p^{ek} / p^{ek}_{p} \le 0.0001$.
- 1 34. The electrokinetic device of claim 28, wherein said conducting conduit
- 2 hydrodynamic conductance, k_c , is greater than or equal to the hydrodynamic
- 3 conductance, k_p , of at least one of said pumping conduits.
- 1 35. The electrokinetic device of claim 34, wherein $k_c/k_p \ge 2$.
- 1 36. The electrokinetic device of claim 35, wherein $k_c/k_p \ge 10$.
- 1 37. The electrokinetic device of claim 36, wherein $k_c/k_p \ge 100$.
- 1 38. The electrokinetic device of claim 37, wherein $k_c/k_p \ge 1000$.
- The electrokinetic device of claim 38, wherein $k_c/k_p \ge 10,000$.
- 1 40. The electrokinetic device of claim 28, wherein said conducting conduit
- electrical resistance, R_c , is greater than or equal to the electrical resistance, R_p , of at
- 3 least one of said pumping conduits.
- 1 41. The electrokinetic device of claim 40, wherein $R_c/R_p \ge 2$.
- 1 42. The electrokinetic device of claim 41, wherein $R_c/R_p \ge 5$.
- 1 43. The electrokinetic device of claim 42, wherein $R_c/R_p \ge 10$.
- 1 44. The electrokinetic device of claim 43, wherein $R_c/R_p \ge 100$.
- 1 45. The electrokinetic device of claim 28, wherein at least one of said
- 2 conduits is a microscale conduit.
- 1 46. The electrokinetic device of claim 28, wherein said first electrode is at
- 2 potential V1, said second electrode is at potential V2, said third electrode is at
- 3 potential V3, and said fourth electrode is at potential V4, and wherein at least one of
- 4 the differences (V1 V2) and (V3 V4) is not equal to zero.
- The electrokinetic device of claim 46, wherein V1, V2, and V3 are
- selected so that (V2 V1) and (V3 V2) are oppositely signed.
- 1 48. The electrokinetic device of claim 46, wherein V1, V2, V3, and V4 are
- selected so that (V2 V1) and (V4 V3) are oppositely signed.
- 1 49. The electrokinetic device of claim 46, wherein V1, V2, V3, and V4 are
- selected so that (V2 V1) and (V4 V3) are same signed.
- The electrokinetic device of claim 46, wherein V1 is equal to V4.
- The electrokinetic device of claim 50, wherein said potentials V1 and
- 2 V4 are ground potentials:

- 52. The electrokinetic device of claim 28, wherein said first porous dielectric material is the same as said second porous dielectric material.
- 1 53. The electrokinetic device of claim 28, wherein said first porous 2 dielectric material is different from said second porous dielectric material.
 - 54. The electrokinetic device of claim 53, wherein said first and said second porous dielectric materials have oppositely-signed zeta potentials when contacted with a pumping fluid.
- 1 55. The electrokinetic device of claim 28, wherein said conducting conduit 2 includes a porous material.
 - 56. The electrokinetic device of claim 28, wherein said device is capable of generating an electroosmotic force on an aqueous fluid.
 - 57. The electrokinetic device of claim 28, wherein said device is capable of generating an electroosmotic force on a fluid mixture comprising an aqueous component and an organic component.
 - 58. The electrokinetic device of claim 28, wherein said device is capable of generating 0.05 psi/volt applied across said first and said second pumping conduits.
 - 59. The electrokinetic device of claim 58, wherein said device is capable of generating 2 psi/volt applied across said first and said second pumping conduits.
 - 60. An electrokinetic device, comprising:
- a first pumping conduit having a first end and a second end, and including a first porous dielectric material;
 - a first conducting conduit having a first end and a second end, said first pumping conduit second end and said first conducting conduit first end connecting at a first junction;
 - a second pumping conduit having a first end and a second end, and including a second porous dielectric material, said second pumping conduit first end connecting to said first conducting conduit second end at a second junction;
- a second conducting conduit having a first end and a second end, said second
 pumping conduit second end connecting to said second conducting conduit first end at
 a third junction; and
- an odd number of electrodes in electrical communication with said pumping conduits and said conducting conduits.
- 1 61. The electrokinetic device of claim 60, wherein said odd number of electrodes comprises a first electrode at potential VI in electrical communication with

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- 3 said first pumping conduit first end, a second electrode at potential V2 in electrical
- 4 communication with said first junction, a third electrode at potential V3 in electrical
- 5 communication with said second junction, a fourth electrode at potential V4 at said
- 6 third junction, and a fifth electrode at potential V5 at said second conducting conduit
- second end, and wherein at least one of the differences (V1 V2) and (V3 V4) does
- 8 not equal zero.

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- 1 62. The electrokinetic device of claim 61, wherein V2 does not equal V3.
- 1 63. The electrokinetic device of claim 61, wherein V4 does not equal V5.
- The electrokinetic device of claim 61, wherein V1, V2, V4, and V5 are selected so that (V2 V1) and (V5 V4) are oppositely signed.
- 1 65. The electrokinetic device of claim 61, wherein V1 is equal to V5.
- 1 66. The electrokinetic device of claim 65, wherein said potentials V1 and 2 V5 are ground potentials.
- 1 67. The electrokinetic device of claim 60, wherein any of said conducting conduits includes a porous material.
 - 68. The electrokinetic device of claim 60, wherein said device is capable of generating an electroosmotic force on an aqueous fluid.
 - 69. The electrokinetic device of claim 60, wherein said device is capable of generating an electroosmotic force on a fluid mixture comprising an aqueous component and an organic component.
 - 70. The electrokinetic device of claim 60, wherein said device is capable of generating 0.05 psi/volt applied across said first and said second pumping conduits.
 - 71. The electrokinetic device of claim 60, wherein said device is capable of generating 2 psi/volt applied across said first and said second pumping conduits.
- The electrokinetic device of claim 60, wherein the hydrodynamic conductance, k_c , of at least one of said conducting conduits is greater than the hydrodynamic conductance, k_p , of at least one of said pumping conduits.
- The electrokinetic device of claim 72, wherein $k_c/k_p \ge 2$.
- The electrokinetic device of claim 73, wherein $k_c/k_p \ge 10$.
- The electrokinetic device of claim 74, wherein $k_c/k_p \ge 100$.
- The electrokinetic device of claim 75, wherein $k_c/k_p \ge 1000$.
- The electrokinetic device of claim 76, wherein $k_c/k_p \ge 10,000$.

- The electrokinetic device of claim 60, wherein the electrokinetic
- 2 pressure value, p_c^{ek} , of at least one of said conducting conduits is less than the
- 3 electrokinetic pressure value, p_p^{ek} , of at least one of said pumping conduits.
- The electrokinetic device of claim 78, wherein $p^{ek} / p^{ek}_{p} \le 0.5$.
- 1 80. The electrokinetic device of claim 79, wherein $p^{ek} / p^{ek}_{p} \le 0.1$.
- 1 81. The electrokinetic device of claim 80, wherein $p^{ek} / p^{ek} \ge 0.01$.
- 1 82. The electrokinetic device of claim 81, wherein $p^{ek} \sqrt{p^{ek}}_p \le 0.001$.
- 1 83. The electrokinetic device of claim 82, wherein $p^{ek} / p^{ek}_{p} \le 0.0001$.
- 1 84. The electrokinetic device of claim 60, wherein the electrical resistance,
- 2 R_c , of at least one of said conducting conduits is greater than or equal to the electrical
- 3 resistance, R_p , of at least one of said pumping conduits.
- 1 85. The electrokinetic device of claim 84, wherein $R_c/R_p \ge 2$.
- 1 86. The electrokinetic device of claim 85, wherein $R_c/R_p \ge 5$.
- 1 87. The electrokinetic device of claim 86, wherein $R_c/R_p \ge 10$.
- 1 88. The electrokinetic device of claim 87, wherein $R_c/R_p \ge 100$.
- 1 89. The electrokinetic device of claim 60, wherein said odd number of
- 2 electrodes comprises a first electrode at potential VI in electrical communication with
- 3 said first pumping conduit first end, and an N^{th} electrode at potential VN in electrical
- 4 communication with a second end of a terminal conducting conduit.
- 1 90. The electrokinetic device of claim 89, wherein VI is equal to VN.
- 1 91. The electrokinetic device of claim 90, wherein said potentials V1 and
- 2 VN are ground potentials.
- 1 92. A method of controlling the flow of a fluid, comprising:
- 2 contacting said pumping conduit first end of the electrokinetic device of
- 3 claim 1 with a fluid; and
- 4 supplying potential V1 to a first electrode in electrical communication with
- 5 said pumping conduit first end, potential V2 to a second electrode in electrical
- 6 communication with said junction, and potential V3 to a third electrode in electrical
- 7 communication with said conducting conduit second end.
- 1 93. The method of claim 92, wherein V1 does not equal V2.
- 1 94. The method of claim 92, wherein V3 does not equal V2.
- The method of claim 92, wherein V1, V2, and V3 are selected so that
- 2 (V2 V1) and (V3 V2) are oppositely signed.
- 1 96. The method of claim 92, wherein V1 is equal to V3.

- 1 97. The method of claim 96, wherein said potentials V1 and V3 are ground
- 2 potentials.
- 1 98. The method of claim 92, further comprising supplying a pressure-
- 2 driven flow to said pumping conduit, and modulating said pressure-driven flow by an
- 3 electroosmotically-driven flow component generated within said pumping conduit.
- 1 99. A method of controlling the flow of a fluid, comprising:
- 2 contacting at least one end of said first pumping conduit or said second
- 3 pumping conduit of the electrokinetic device of claim 28 with a fluid; and
- supplying potential V1 to a first electrode in electrical communication with
- 5 said first pumping conduit first end, potential V2 to a second electrode in electrical
- 6 communication with said first junction, potential V3 to a third electrode in electrical
- 7 communication with said second junction, and potential V4 to a fourth electrode in
- 8 electrical communication with said second pumping conduit second end.
- 1 100. The method of claim 99, wherein at least one of said differences (VI -
- 2 V2) and (V3 V4) is not equal to zero.
- 1 101. The method of claim 99, wherein at least one of said differences (VI –
- 2 V2) and (V3 V4) is less than 200 volts.
- 1 102. The method of claim 99, wherein V1, V2, and V3 are selected so that
- 2 (V2 V1) and (V3 V2) are oppositely signed.
- 1 103. The method of claim 99, wherein V1, V2, V3, and V4 are selected so
- 2 that (V2 V1) and (V4 V3) are oppositely signed.
- 1 104. The method of claim 99, wherein V1, V2, V3, and V4 are selected so
- 2 that (V2 V1) and (V4 V3) are same signed.
- 1 105. The method of claim 99, wherein V1 is equal to V4.
- 1 106. The method of claim 105, wherein said potentials V1 and V4 are
- 2 ground potentials.
- 1 107. The method of claim 99, further comprising supplying a pressure-
- 2 driven flow to said device, and modulating said pressure-driven flow by an
- 3 electroosmotically-driven flow component generated within said first or said second
- 4 pumping conduit.
- 1 108. A method of controlling the flow of a fluid, comprising:
- 2 contacting at least one end of said first pumping conduit or said second
- 3 pumping conduit of the electrokinetic device of claim 60 with a fluid; and

- 4 supplying potential V1 to a first electrode in electrical communication with
- 5 said first pumping conduit first end, potential V2 to a second electrode in electrical
- 6 communication with said first junction, potential V3 to a third electrode in electrical
- 7 communication with said second junction, potential V4 to a fourth electrode in
- 8 electrical communication with said third junction, and potential V5 to said second
- 9 conducting conduit second end.
- 1 109. The method of claim 108, wherein at least one of the differences (VI -
- 2 V2) and (V3 V4) is not equal to zero.
- 1 110. The method of claim 108, wherein V2 does not equal V3.
- 1 111. The method of claim 108, wherein V4 does not equal V5.
- 1 112. The method of claim 108, wherein V1, V2, V4, and V5 are selected so
- 2 that (V2 V1) and (V5 V4) are oppositely signed.
- 1 113. The method of claim 108, wherein V1 is equal to V5.
- 1 114. The method of claim 113, wherein said potentials V1 and V5 are
- 2 ground potentials.
- 1 115. The method of claim 108, further comprising supplying a pressure-
- 2 driven flow to said device, and modulating said pressure-driven flow by an
- 3 electroosmotically-driven flow component generated within said first or said second
- 4 pumping conduit.
- 1 116. An electrokinetic device, comprising:
- a pumping conduit having a first end and a second end, and including a porous
- 3 dielectric material;
- 4 a conducting conduit having a first end and a second end, said pumping
- 5 conduit second end and said conducting conduit first end connecting at a junction; and
- a first electrode at potential V1 in electrical communication with said pumping
- 7 conduit first end, a second electrode at potential V2 in electrical communication with
- 8 said junction, and a third electrode at potential V3 in electrical communication with
- 9 said conducting conduit second end, wherein a predetermined electroosmotic flow
- may be generated by said device with at least one of said potentials V1 and V3
- 11 assuming an arbitrary value.
- 1 The electrokinetic device of claim 116, wherein V1 does not equal V2.
- 1 118. The electrokinetic device of claim 116, wherein V3 does not equal V2.
- 1 119. The electrokinetic device of claim 116, wherein V1, V2, and V3 are
- selected so that (V2 VI) and (V3 V2) are oppositely signed.

- 1 120. The electrokinetic device of claim 116, wherein V1 is equal to V3.
- 1 121. The electrokinetic device of claim 120, wherein said potentials V1 and 2 V3 are ground potentials.
- 1 122. The electrokinetic device of claim 116, wherein said conducting 2 conduit includes a porous material.
- 1 123. The electrokinetic device of claim 116, wherein said conducting 2 conduit hydrodynamic conductance, k_c , is greater than said pumping conduit 3 hydrodynamic conductance, k_p .
- 1 124. The electrokinetic device of claim 123, wherein $k_c/k_p \ge 2$.
- 1 125. The electrokinetic device of claim 124, wherein $k_c/k_p \ge 10$.
- 1 126. The electrokinetic device of claim 125, wherein $k_c/k_p \ge 100$.
- 1 127. The electrokinetic device of claim 126, wherein $k_c/k_p \ge 1000$.
- 1 128. The electrokinetic device of claim 127, wherein $k_c/k_p \ge 10,000$.
- 1 129. The electrokinetic device of claim 116, wherein said conducting conduit electrokinetic pressure value, p_c^{ek} , is less than said pumping conduit electrokinetic pressure value, p_c^{ek} .
- 1 130. The electrokinetic device of claim 129, wherein $p^{ek} / p^{ek}_{p} \le 0.5$.
- 1 131. The electrokinetic device of claim 130, wherein $p^{ek} \sqrt{p^{ek}}_p \le 0.1$.
- 1 132. The electrokinetic device of claim 131, wherein $p^{ek} / p^{ek}_{p} \le 0.01$.
- 1 133. The electrokinetic device of claim 132, wherein $p^{ek} / p^{ek}_{p} \le 0.001$.
- 1 134. The electrokinetic device of claim 133, wherein $p^{ek} / p^{ek}_{p} \le 0.0001$.
- 1 135. The electrokinetic device of claim 116, wherein said conducting 2 conduit electrical resistance, R_c , is greater than or equal to said pumping conduit 3 electrical resistance, R_p .
- 1 136. The electrokinetic device of claim 135, wherein $R_c/R_p \ge 2$.
- 1 137. The electrokinetic device of claim 136, wherein $R_c/R_p \ge 5$.
- 1 138. The electrokinetic device of claim 137, wherein $R_c/R_p \ge 10$.
- 1 139. The electrokinetic device of claim 138, wherein $R_c/R_p \ge 100$.
- 1 140. The electrokinetic device of claim 116, wherein said device is capable 2 of generating 0.05 psi/volt applied across said pumping conduit.
- 1 141. The electrokinetic device of claim 140, wherein said device is capable 2 of generating 0.1 psi/volt applied across said pumping conduit.
- 1 142. The electrokinetic device of claim 141, wherein said device is capable 2 of generating 1 psi/volt applied across said pumping conduit.

- 143. The electrokinetic device of claim 142, wherein said device is capable of generating 10 psi/volt applied across said pumping conduit.
 - 144. An electrokinetic device, comprising:

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- a first pumping conduit having a first end and a second end, and including a first porous dielectric material;
- a first conducting conduit having a first end and a second end, said first
 pumping conduit second end and said first conducting conduit first end connecting at
 a first junction;
- a second pumping conduit having a first end and a second end, and including a second porous dielectric material, said second pumping conduit first end connecting to said first conducting conduit second end at a second junction;
 - a second conducting conduit having a first end and a second end, said second pumping conduit second end connecting to said second conducting conduit first end at a third junction; and
- a first electrode at potential V1 in electrical communication with said first
 pumping conduit first end, a second electrode at potential V2 in electrical
 communication with said first junction, a third electrode at potential V3 in electrical
 communication with said second junction, a fourth electrode at potential V4 in
 electrical communication with said third junction, and a fifth electrode at potential V5
 in electrical communication with said second conducting channel second end, wherein
- 19 a predetermined electroosmotic flow may be generated by said device with at least
- one of said potentials V1 and V5 assuming an arbitrary value.
- 1 145. The device of claim 144, wherein at least one of the differences (VI -
- 2 V2) and (V3 V4) does not equal zero.
- 1 146. The electrokinetic device of claim 144, wherein V2 does not equal V3.
- 1 147. The electrokinetic device of claim 144, wherein V4 does not equal V5.
- 1 148. The electrokinetic device of claim 144, wherein V1, V2, V4, and V5 are selected so that (V2 V1) and (V5 V4) are oppositely signed.
- 1 149. The electrokinetic device of claim 144, wherein V1 is equal to V5.
- 1 150. The electrokinetic device of claim 149, wherein said potentials V1 and 2 V5 are ground potentials.
- 1 151. The electrokinetic device of claim 144, wherein any of said conducting 2 conduits includes a porous material.

- 1 152. The electrokinetic device of claim 144, wherein said device is capable
- 2 of generating 0.05 psi/volt applied across said first and said second pumping conduits.
- 1 153. The electrokinetic device of claim 152, wherein said device is capable of generating 2 psi/volt applied across said first and said second pumping conduits.
- 1 154. The electrokinetic device of claim 144, wherein the hydrodynamic conductance, k_c , of at least one of said conducting conduits is greater than the hydrodynamic conductance, k_p , of at least one of said pumping conduits.
- 1 155. The electrokinetic device of claim 154, wherein $k_c/k_p \ge 2$.
- 1 156. The electrokinetic device of claim 155, wherein $k_c/k_p \ge 10$.
- 1 157. The electrokinetic device of claim 156, wherein $k_c/k_p \ge 100$.
- 1 158. The electrokinetic device of claim 157, wherein $k_c/k_p \ge 1000$.
- 1 159. The electrokinetic device of claim 158, wherein $k_c/k_p \ge 10,000$.
- 1 160. The electrokinetic device of claim 144, wherein the electrokinetic 2 pressure value, p^{ek}_{c} , of at least one of said conducting conduits is less than the 3 electrokinetic pressure value, p^{ek}_{p} , of at least one of said pumping conduits.
- 1 161. The electrokinetic device of claim 160, wherein $p^{ek} / p^{ek}_{p} \le 0.5$.
- 1 162. The electrokinetic device of claim 161, wherein $p^{ek} \sqrt{p^{ek}}_p \le 0.1$.
- 1 163. The electrokinetic device of claim 162, wherein $p^{ek} / p^{ek}_{p} \le 0.01$.
- 1 164. The electrokinetic device of claim 163, wherein $p^{ek} / p^{ek}_{p} \le 0.001$.
- 1 165. The electrokinetic device of claim 164, wherein $p^{ek} / p^{ek}_{p} \le 0.0001$.
- 1 166. The electrokinetic device of claim 144, wherein the electrical resistance, R_c, of at least one of said conducting conduits is greater than or equal to the conduction of the electrokinetic device of claim 144, wherein the electrical resistance, R_c, of at least one of said conducting conduits is greater than or equal to the electrokinetic device of claim 144, wherein the electrical resistance, R_c, of at least one of said conducting conduits is greater than or equal to the electrical resistance.
 - resistance, R_c , of at least one of said conducting conduits is greater than or equal to the electrical resistance, R_p , of at least one of said pumping conduits.
- 1 167. The electrokinetic device of claim 166, wherein $R_c/R_p \ge 2$.
- 1 168. The electrokinetic device of claim 167, wherein $R_c/R_p \ge 5$.
- 1 169. The electrokinetic device of claim 168, wherein $R_o/R_p \ge 10$.
- 1 170. The electrokinetic device of claim 169, wherein $R_c/R_p \ge 100$.